

L Number	Hits	Search Text	DB	Time stamp
1	2	20040004863.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:10
2	1067	257/390.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:35
3	323	257/391.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:29
4	1760	438/128.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:31
5	372	438/587.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:31
6	192	438/588.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:31
7	270	438/598.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:32
8	176	438/599.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:32
9	733	438/129.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:33
10	69	257/920.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:47
11	0	6420231.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:47
12	2	6420231.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/01 06:47
-	583	((plurality or array) adj nonvolatile adj memory adj cells)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:54
-	885	((plurality or array) adj nonvolatile adj memory)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 16:57

-	58	((plurality or array) adj nonvolatile adj memory) and 257/\$.ccls. and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:02
-	4	((multiple) adj nonvolatile adj memory) and 257/\$.ccls. and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:03
-	1	((plural) adj nonvolatile adj memory) and 257/\$.ccls. and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:07
-	861	257/207.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:19
-	920	257/208.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:27
-	344	257/209.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:31
-	363	257/210.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:36
-	639	257/211.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:45
-	105	257/905.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:46
-	257	257/909.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:46
-	0	((plurality or array) adj nonvolatile adj memory) and bitline and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:55
-	18	((plurality or array) adj nonvolatile adj memory) and bitline and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:00
-	0	((plural or multiple) adj nonvolatile adj memory) and bitline and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:00
-	0	((multiplicity or multi) adj nonvolatile adj memory) and bitline and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:01

-	97	(nonvolatile adj memory) and bitline and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:08
-	6	(nonvolatile adj memory) and bitline and rows and columns and (field adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:29
-	56	(memory adj array) and bitline and rows and columns and (field adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:19
-	0	(floating adj gates adj connected adj together) and bitline and rows and columns and (field adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:19
-	0	(gates adj connected adj together) and bitline and rows and columns and (field adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:19
-	10	(gates adj connected) and bitline and rows and columns and (field adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:20
-	94	(gates adj connected) and bitline and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:22
-	340	(gates adj connected) and (bit adj line) and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:23
-	25	(nonvolatile adj memory) and (bit adj line) and rows and columns and (field adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:31
-	210	(memory adj array) and (bit adj line) and rows and columns and (field adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:35
-	850	(memory adj array) and (bit adj line) and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:49
-	340	(gates adj connected) and (bit adj line) and rows and columns and (field adj oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:50